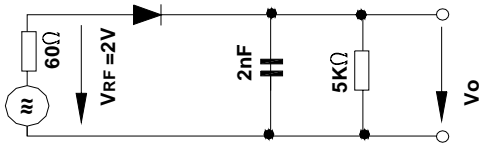




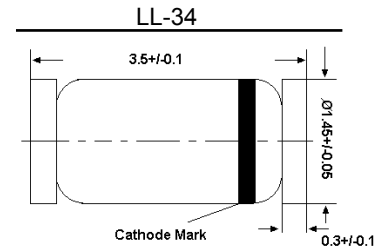
LL4148

Silicon Epitaxial Planar Switching Diode

Fast switching diode in MiniMELF case especially suited for automatic surface mounting



Rectification Efficiency Measurement Circuit



Glass case MiniMELF Dimensions in mm

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|---|-------------|--|------------------|
| Peak Reverse Voltage | V_{RM} | 100 | V |
| Reverse Voltage | V_R | 75 | V |
| Average Rectified Forward Current | $I_{F(AV)}$ | 200 | mA |
| Non-repetitive Peak Forward Surge Current | I_{FSM} | 0.5 1 4 | A |
| | | at $t = 1\text{ s}$ at $t = 1\text{ ms}$ at $t = 1\text{ }\mu\text{s}$ | |
| Power Dissipation | P_{tot} | 500 ¹⁾ | mW |
| Junction Temperature | T_j | 175 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | - 65 to + 175 | $^\circ\text{C}$ |

¹⁾ Valid provided that electrodes are kept at ambient temperature.

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

| Parameter | Symbol | Min. | Max. | Unit |
|--|-------------------------|-------------|--------------------|--------------------------------------|
| Forward Voltage at $I_F = 10\text{ mA}$ | V_F | - | 1 | V |
| Leakage Current at $V_R = 20\text{ V}$ at $V_R = 75\text{ V}$ at $V_R = 20\text{ V}$, $T_j = 150\text{ }^\circ\text{C}$ | I_R I_R I_R | - - - | 25 5 50 | nA μA μA |
| Reverse Breakdown Voltage tested with 100 μA Pulses | $V_{(BR)R}$ | 100 | - | V |
| Capacitance at $V_R = 0$, $f = 1\text{ MHz}$ | C_{tot} | - | 4 | pF |
| Voltage Rise when Switching ON tested with 50 mA Forward Pulses $t_p = 0.1\text{ s}$, Rise Time < 30 ns, $f_p = 5\text{ to }100\text{ KHz}$ | V_{fr} | - | 2.5 | V |
| Reverse Recovery Time at $I_F = 10\text{ mA}$ to $I_R = 1\text{ mA}$, $V_R = 6\text{ V}$, $R_L = 100\text{ }\Omega$ | t_{rr} | - | 4 | ns |
| Thermal Resistance Junction to Ambient Air | R_{thA} | - | 0.35 ¹⁾ | K/mW |
| Rectification Efficiency at $f = 100\text{ MHz}$, $V_{RF} = 2\text{ V}$ | η_V | 0.45 | - | - |

¹⁾ Valid provided that electrodes are kept at ambient temperature.





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